Old Company Name in Catalogs and Other Documents

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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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MOS FIELD EFFECT TRANSISTOR NP82N04PDG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP82N04PDG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING PACKING		PACKAGE	
NP82N04PDG-E1-AY	Pure Sn (Tin) Tape		TO-263 (MP-25ZP)	
NP82N04PDG-E2-AY		800 p/reel	typ. 1.5 g	

FEATURES

• Super low on-state resistance $R_{DS(on)1} = 3.5 \text{ m}\Omega \text{ MAX}$. (VGs = 10 V, ID = 41 A)

- $R_{DS(on)2} = 8.0 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, \text{ ID} = 41 \text{ A})$
- Low Ciss Ciss = 6000 pF TYP.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	40	V			
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V			
Drain Current (DC) (Tc = 25°C)	D(DC)	±82	А			
Drain Current (pulse) ^{Note1}	D(pulse)	±328	А			
Total Power Dissipation (Tc = 25° C)	P T1	143	W			
Total Power Dissipation (T _A = 25° C)	Pt2	1.8	W			
Channel Temperature	Tch	175	°C			
Storage Temperature	Tstg	–55 to +175	°C			
Repetitive Avalanche Current Note2	IAR	43	А			
Repetitive Avalanche Energy Note2	Ear	185	mJ			
Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%						
2. T _{ch} \leq 150°C, V _{DD} = 20 V, R _G = 25 Ω , V _{GS} = 20 \rightarrow 0 V						





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Rth(ch-C)

Rth(ch-A)

1.05

83.3

°C/W

°C/W

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Document No. D18396EJ1V0DS00 (1st edition) Date Published September 2006 NS CP(K) Printed in Japan

THERMAL RESISTANCE

Channel to Case Thermal Resistance

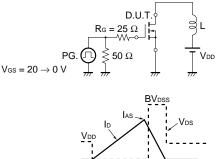
Channel to Ambient Thermal Resistance

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 40 V, V _{GS} = 0 V			1	μA
Gate Leakage Current	lgss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	$V_{\text{GS(th)}}$	V _{DS} = V _{GS} , I _D = 250 μA	1.4	1.8	2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 41 A	20	47		S
Drain to Source On-state Resistance	RDS(on)1	V _{GS} = 10 V, I _D = 41 A		2.9	3.5	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 41 A		4.1	8.0	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		6000	9000	pF
Output Capacitance	Coss	V _{GS} = 0 V		580	870	рF
Reverse Transfer Capacitance	Crss	f = 1 MHz		370	670	pF
Turn-on Delay Time	td(on)	V _{DD} = 20 V, I _D = 41 A		26	60	ns
Rise Time	tr	V _{GS} = 10 V		68	170	ns
Turn-off Delay Time	td(off)	R _G = 0 Ω		73	150	ns
Fall Time	tr			11	30	ns
Total Gate Charge	QG	V _{DD} = 32 V		100	150	nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V		19		nC
Gate to Drain Charge	Qgd	ID = 82 A		32		nC
Body Diode Forward Voltage	VF(S-D)	IF = 82 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 82 A, VGS = 0 V		43		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		47		nC

ELECTRICAL CHARACTERISTICS (TA = 25°C)

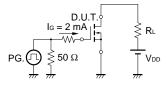
TEST CIRCUIT 1 AVALANCHE CAPABILITY

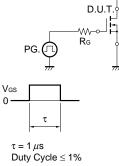
TEST CIRCUIT 2 SWITCHING TIME

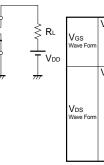


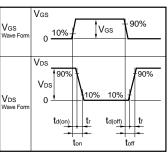
Starting Tch

TEST CIRCUIT 3 GATE CHARGE

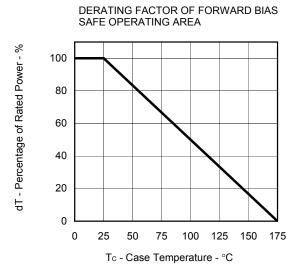


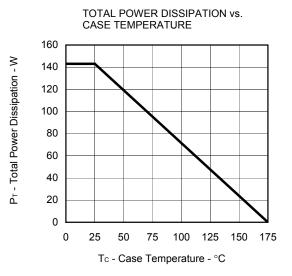




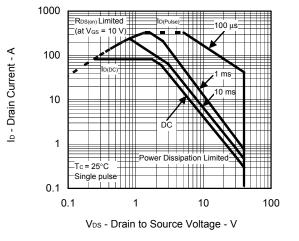


TYPICAL CHARACTERISTICS (TA = 25°C)

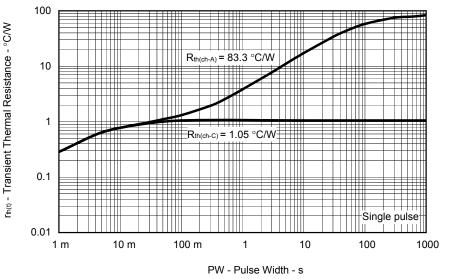


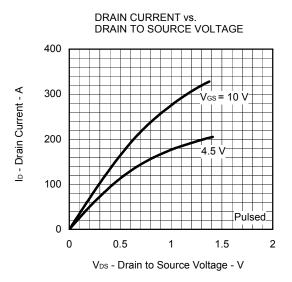


FORWARD BIAS SAFE OPERATING AREA

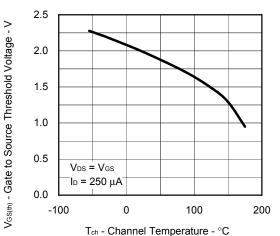


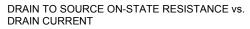
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

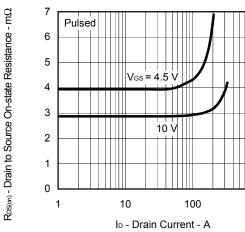




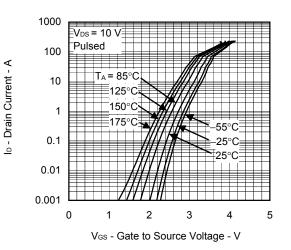
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



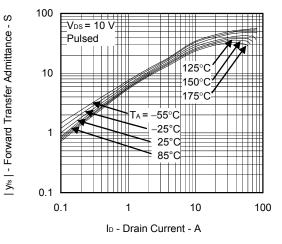


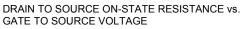


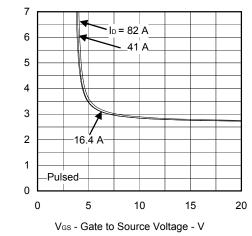
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT





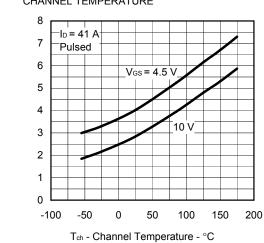


Data Sheet D18396EJ1V0DS

1000

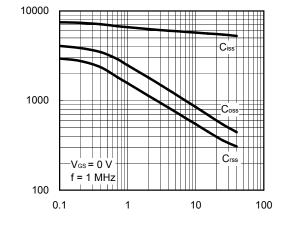
 $R_{DS(m)}$ - Drain to Source On-state Resistance - m Ω

 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$



DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

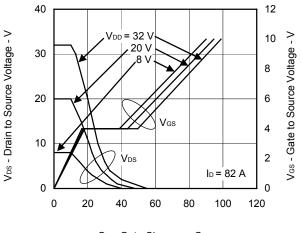
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



Ciss, Coss, Crss - Capacitance - pF

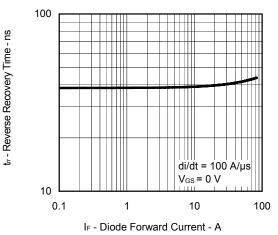
V_{DS} - Drain to Source Voltage - V

DYNAMIC INPUT/OUTPUT CHARACTERISTICS



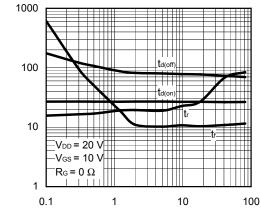
QG - Gate Charge - nC

REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





SWITCHING CHARACTERISTICS



ID - Drain Current - A

SOURCE TO DRAIN DIODE FORWARD VOLTAGE

4.5 V

0

1

Vgs = 10 V

0.5

VF(S-D) - Source to Drain Voltage - V

IF - Diode Forward Current - A

1000

100

10

1

0.1

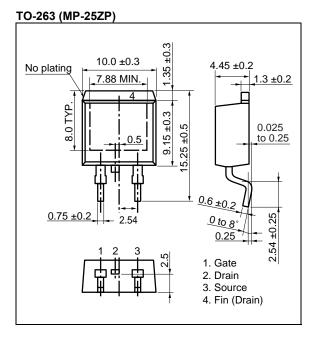
0.01

0

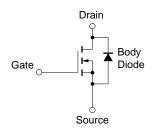
Pulsed

1.5

PACKAGE DRAWING (Unit: mm)



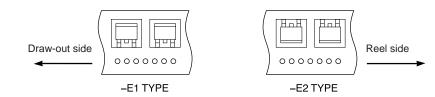
EQUIVALENT CIRCUIT



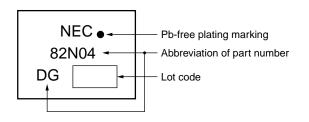
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP82N04PDG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below	IR60-00-3
	Time at maximum temperature: 10 seconds or less	
	Time of temperature higher than 220°C: 60 seconds or less	
	Preheating time at 160 to 180°C: 60 to 120 seconds	
	Maximum number of reflow processes: 3 times	
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	
Partial heating	Maximum temperature (Pin temperature): 350°C or below	P350
	Time (per side of the device): 3 seconds or less	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less	

Caution Do not use different soldering methods together (except for partial heating).

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